

# Embedded Control of LCL Resonant Converter Analysis, Design, Simulation and Experimental Results

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### Abstract

The Objective of this paper is to give more insight into CCM Operation of the LCL Converter to obtain optimum design using state-space analysis and to verify the results using PSPICE Simulation for wide variation in loading conditions. LCL Resonant Full Bridge Converter (RFB) is a new, high performance DC-DC converter. High frequency dc-dc resonant converters are widely used in many space and radar power supplies owing to their small size and lightweight. The limitations of two element resonant topologies can be overcome by adding a third reactive element termed as modified series resonant converter (SRC). A three element resonant converter capable of driving voltage type load with load independent operation is presented. We have used embedded based triggering circuit and the embedded 'C' Program is checked in Keil Software and also triggering circuit is simulated in PSPICE Software. To compare the simulated results with hardware results and designed resonant converter is 200W and the switching frequency is 50 KHz.

Keywords: Continuous Current Mode, High-frequency Link, MOSFET, Zero-Current Switching, Resonant Converter

# 1. Introduction

In Converter applications solid-state devices are operated at very high frequency. So the switching losses are more than the conduction losses [1] and it becomes a major cause of poor efficiency of the converter circuit [2,3]. This leads to the search of a converter that can provide high efficiency [4], lower component stress [5], high power, high switching frequency, lightweight as well as low cost and high power operation [6]. In order to keep the switching power losses low and to reduce the problem of EMI, the resonant converter is suggested [7–9].

The resonant converter is a new high performance DC-DC converter [10]. A resonant converter can be operated either below resonant (leading p.f) mode or above resonant (lagging p.f) mode. The most popular resonant converter configuration is series resonant converter

(SRC), parallel resonant converter (PRC) and series parallel resonant converter (SPRC). A SRC has high efficiency from full load to very light loads [11,12]. Where as a PRC has lower efficiency at reduced loads due to circulating currents [13,14].

The limitations of two element resonant topologies can be over come by adding a third reactive element, termed as modified SRC. SRC has voltage regulation problems in light load conditions [15,16]; to over come this problem the modified SRC is presented. The LCL-resonant converter using voltage source type load has nearly load independent output voltage under some operating conditions [17]. These converters are analyzed by using state-space approach. Based on this analysis, a simple design procedure is proposed. Using PSPICE software simulates the LCL-Resonant Full Bridge Converter. The proposed results are improved power densities in air borne applications.

### 2. Modified Series Resonant Converter

A Series Resonant Full Bridge Converter (SRC) modified by adding an inductor in parallel with the transformer primary is presented. This configuration is referred to as an "LCL Resonance Full Bridge Converter". A three element (LCL) Resonance Full Bridge Converter capable of driving voltage type load with load independent operation is analyzed. In such a converter has load independent characteristics, there is no analysis or design procedure available. It is shown in this project that these type of converter requires a very narrow range of frequencies control from full load to very light loads and can operate with load short circuit while processing the desirable features of the SRC. The resonance converter operating in the above resonance (lagging power factor) mode has a number of advantages (e.g. No need for lossy snubbers and di/dt limiting inductors). Therefore, the proposed converter configuration in the above resonance mode, State-space approach is used for the converter analysis. A modified SRFB Converter with capacity output filter has been presented.

### 3. Circuit Description

The resonant tank of this converter consists of three reactive energy storage elements (LCL) as opposed to the conventional resonant converter that has only two elements. The first stage converts a dc voltage to a high frequency ac voltage. The second stage of the converter is to convert the ac power to dc power by suitable high frequency rectifier and filter circuit. Power from the resonant circuit is taken either through a transformer in series with the resonant circuit (or) across the capacitor comprising the resonant circuit as shown in Fig.1. In both cases the high frequency feature of the link allows the use of a high frequency transformer to provide voltage transformation and ohmic isolation between the dc source and the load.

In Series Resonant Converter (SRC), the load voltage can be controlled by varying the switching frequency or by varying the phase difference between the two inverts where the switching frequency of each is fixed to the resonant frequency. The phase domain control scheme is suitable for wide variation of load condition because the output voltage is independent of load.

The basic circuit diagram of the full bridge LCL resonant converter with capacitive output filter is shown in Figure 1.

The major advantages of this series link load SRC is that the resonating blocks the DC supply voltage and there is no commutation failure if MOSFET are used as switches. Moreover, since the dc current is absent in the primary side of the transformer, there is no possibility of current balancing. Another advantage of this circuit is that the device currents are proportional to load current. This increases the efficiency of the converter at light loads to some extent because the device losses also decrease with the load current. Close to the resonant frequency the load current becomes maximum for a fixed load resistance. If the load gets short at this condition very large current would flow through the circuit. This may damage the switching devices. To make the circuit short circuit proof, the operating frequency should be changed.

The filter circuit has some disadvantage. It is a capacitor input filter and the capacitor must carry large ripple current. It may be as much as 48% of the load current. The disadvantage is more severe for large output current with low voltage. Therefore, this circuit is suitable for high voltage low current regulators.

# 4. State – Space Analysis

### 4.1. Assumptions in State Space Analysis

The following assumptions are made in the state spare analysis of the LCL Resonant Full Bridge Converter.

1) The switches, diodes, inductors, and capacitors used are ideal.

2) The effect of snubber capacitors is neglected.



Figure 1. DC- DC converter employing LCL full bridge operating in CCM.



Figure 2. Equivalent circuit model of LCL RFBC.

3) Losses in the tank circuit and neglected.

4) Dc supply used is smooth.

d

dt

5) Only fundamental components of the waveforms are used in the analysis.

6) Ideal hf transformer with turns ration n = 1.

The equivalent circuit shown in Figure 2 is used for the analysis. The vector space equation for the converter is:

$$X = AX + BU$$
(1)

where m and n take values as shown in Table 1 representing different modes of continuous and discontinuous conduction.

However, in the discontinuous conduction mode 7, the converter operates like a simple SRC with resonant frequency, fo and  $i_{Ls}=i_{Lp}$ . It is interesting to note that in all six continuous conduction modes, the voltage  $V_{LP}$  is clamped and the current  $i_{Lp}$  is independent of the other two state variables. As a result, the 3<sup>rd</sup> order matrix (1) can be reduced to second order equation for which the solutions are readily available [2].

The state equation describing period  $tp_{-1} < t < tp$ 

$$mVg = Ls (di_{Ls}/dt) + nVo-Vc$$
 (2)

$$(di_{Ls}/dt) = (m/Ls)Vg - (nVo/Ls) - (1/Ls)Vc$$
 (3)

$$dV_{Cs}/dt) = (1/Cs) i_{Ls}$$
 (4)

$$(di_{Lp}/dt) = (nVo/Lp)$$
(5)

 $=\frac{1}{S(S^{2}+\dot{\omega}^{2})}\begin{pmatrix}S^{2}&-S/C&0\\S/Ls&S^{2}&0\\0&0&S^{2}+\dot{\omega}^{2}\end{pmatrix}$ 

 $\phi(S) = \begin{pmatrix} S/S^2 + \dot{\omega}^2 & -1/Cs(S^2 + \dot{\omega}^2) & 0\\ 1/Ls(S^2 + \dot{\omega}^2) & S/(S^2 + \dot{\omega}^2) & 0\\ 0 & 0 & 1/S \end{pmatrix}$ 

 $\phi(t) = \begin{pmatrix} \cos \omega t & -\sin \omega_1 t / Cs \, \omega_1 & 0 \\ \sin \omega_1 t / Ls \, \omega_1 & \cos \omega_1 t & 0 \end{pmatrix}$ 

State matrix: X = AX + BU

 $Adj[SI - A] = \begin{pmatrix} S^{2} & -S/C & 0\\ S/Ls & S^{2} & 0\\ 0 & 0 & S^{2} + \dot{\omega}^{2} \end{pmatrix}$ 

$$\begin{pmatrix} i_{Ls} \\ V_{cs} \\ i_{Lp} \end{pmatrix} = \begin{pmatrix} 0 & (-1/L_s) & 0 \\ 1/C_s & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix} + \begin{pmatrix} i_{Ls}(t) \\ V_{cs}(t) \\ i_{Lp}(t) \end{pmatrix} \begin{pmatrix} (m/L_s) & (-n/L_s) \\ 0 & 0 \\ 0 & n/L_p \end{pmatrix} \begin{pmatrix} V_g \\ V_o \end{pmatrix}$$
(6)

Table 1. Different mode of operation.

Mode	m	n	So	id
1	+1	+1	ON	> 0
2	0	+1	ON	> 0
3	-1	+1	ON	> 0
4	+1	-1	ON	> 0
5	0	-1	ON	> 0
6	-1	-1	ON	> 0
7	0	-	OFF	0
8	+1	-	OFF	0
9	-1	-	OFF	0

The sum of the zero input response and the zero state response.

$$X(t) = [\phi(t) [X (o)]] + L^{-1} (\phi(s) B[U(s)]$$
(7)

The transition matrix

$$\phi(t) = L^{-1} [\phi (S)]$$
(8)  
= L<sup>-1</sup> [(SI-A) -1] (9)

$$(S I - A) = S_3 + S \omega 2$$
  
= S  $(S_2 + \omega 2)$  (10)

where 
$$\omega = 1/\sqrt{LC}$$

 $\therefore$  Zero state response, = L<sup>-1</sup> [( $\phi$  (s) B [U (s)]]

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$$= L^{-1} \begin{pmatrix} S/S^{2} + \dot{\omega}^{2} & -1/Cs(S^{2} + \dot{\omega}^{2}) & 0\\ 1/Ls(S^{2} + \dot{\omega}^{2}) & S/(S^{2} + \dot{\omega}^{2}) & 0\\ 0 & 0 & 1/S \end{pmatrix} \begin{pmatrix} m/Ls & -n/Ls\\ 0 & 0\\ 0 & n/Lp \end{pmatrix} \begin{pmatrix} Vg/S\\ Vo/S \end{pmatrix} = \begin{pmatrix} (mVg - nVo)/Zos \sin \dot{\omega}_{1}(t - t_{p-1}) \\ mVg - nVo[1 - \cos \dot{\omega}_{1}(t - t_{p-1})] \\ Vo / Lp(t - t_{p-1}) \end{pmatrix}$$

$$x(t) = [\phi(t) [x(o)] + L^{-1} [\phi(s) B[U(s)]]$$

$$\begin{pmatrix} i_{L_s}(t) \\ V_{cs}(t) \\ i_{L_p}(t) \end{pmatrix} = \begin{pmatrix} \cos \dot{\omega}_1 t(t-t_{p-1}) & \sin \dot{\omega}_1 (t-t_{p-1})/Ls \dot{\omega}_1 & 0 \\ -\sin \dot{\omega}_1 (t-t_{p-1})/Cs \dot{\omega}_1 \cos \dot{\omega} & 1(t-t_{p-1}) & 0 \\ 0 & 0 & 1 \end{pmatrix} \begin{pmatrix} i_{L_s}(t-t_{p-1}) \\ V_{cs}(t-t_{p-1}) \\ i_{L_p}(t-t_{p-1}) \end{pmatrix} + \begin{pmatrix} (mVg - nVo)/Zos \sin \dot{\omega}_1 (t-t_{p-1}) \\ mVg - nVo[1 - \cos \dot{\omega}_1 (t-t_{p-1})] \\ nVo / Lp(t-t_{p-1}) \end{pmatrix}$$

$$I_{Ls}(t) = \cos \omega 1 (t-t_{p-1}) I_{Ls}(t_{p-1}) + (\sin \omega 1(t-t_{p-1}) / Ls \omega 1) VCs(t_{p-1}) + ((mVg-nVo) / Zos) \sin \omega_1(t-t_{p-1})$$
(11)

$$I_{Ls}(t) = I_{Ls}(t_{p-1}) \cos[\omega 1(t - t_{p-1})] + [(mVg - nVo - Vcs(t_{p-1}) / Zos] \sin[\omega_{os}(t - t_{p-1})]$$
(12)

$$V_{cs}(t) = i_{Ls}(t_{p-1}) \operatorname{Zos\,sin}\left[\dot{\omega}_{os}(t - t_{p-1})\right] + (m \operatorname{Vg-nVo}\left[1 - \cos \dot{\omega}_{1}(t - t_{p-1})\right] + \operatorname{Vcs}\left(t_{p-1}\right) \cos\left[\dot{\omega}_{1}(t - t_{p-1})\right]$$
(13)

$$i_{Lp}(t) = i_{Lp}(t_{p-1}) + (n/Lp) Vo(t - t_{p-1})$$
(14)

where,  $t_{p-1}$  is the time at the start of any, ccm.  $t_p$  is the time at the end of the same ccm. Similarly, the solutions for the discontinuous conduction mode are:  $i_{Ls} = i_{Lp}$ .

$$i_{Ls}(t) = i_{Lp}(t) = i_{Ls}(t_{p-1}) \cos \left[ \dot{\omega}_o(t - t_{p-1}) \right] + \left[ (mVg - Vcs(t_{p-1}) / Zo) \sin(t - t_{p-1}) \right]$$
(15)

$$V_{Cs}(t) = i_{Ls}(t_{p-1}) Zo \sin \left[ \dot{\omega}_{o}(t - t_{p-1}) \right] + mVg[1 - \cos[\dot{\omega}_{o}(t - t_{p-1})]] + Vcs(t_{p-1}) \cos \left( \dot{\omega}_{o}(t - t_{p-1}) \right]$$
(16)

where D is the duty cycle =  $\tau / (T_s / 2)$ 

From Mo equation, it can be concluded that the output voltage is not dependent on the load resistance and converter gain follows a sine function. These results are completely validated experimentally by plotting the variation of Mo with duty ratio. At the optimum normalized switching frequency fno, mo is independent of variations in the load resistance for all pulse widths. The deviation increases with reducing values of load resistance or increasing values of load current for the given voltage. This arises because of sensing resistance of 0.5  $\Omega$  used in series with the resonant element for monitoring its and also finite resistance offered by diodes and MOSFET'S in conduction. In order to maintain the output voltage constant at desired value against the variations in the load resistance and supply voltage variations, the pulse width has to be changed in a closed-loop manner. However, the required change in pulse width to maintain constant output voltage against load variations and constant input voltage is very small.

# 5. Design Procedure

# 5.1. Design: (Operating Switching Frequency = 50khz)

It is desired to design the converter with the following specifications:

1) Power output =200W

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2) Minimum input voltage	=100V
3) Minimum output voltage	=125V
4) Maximum load current	= 1.6 A
5) Maximum overload current	=4A
6) Inductance ratio $(K_L)$	= 1

The hf transformer turns ratio assumed to be unity.

The load resistance:

 $R_L$  = Maximum output voltage / maximum output current.

= 100 / 1.6= 62.5 $\cong 63\Omega$ 



Figure 3. Variation of voltage gain with the duty ratio.

The input rms voltage to the diode bridge:

$$(V_{Lp}) = 2\sqrt{2} V_0/\pi$$
 (17)

The input rms current at the input of the diode bridge =  $[\pi/2\sqrt{2}]I_0$  (18)

The reflected ac resistance on the input side of the diode bridge is

$$R_{ac} = V_{LP} / I_d$$

$$V_{LP} / I_d = \left(2\sqrt{2} V_0 / \pi\right) / \left(\pi / 2\sqrt{2}\right) I_0$$

$$= \left(2\sqrt{2} V_0 \times 2\sqrt{2}\right) / \pi \times \pi \times I_0$$
(19)

 $V_{LP} / I_d = 8 V_0 / \pi^2 I_0$ (20)

For maximum power output

$$\sqrt{L_s / C_s} = 8R_L / \pi^2$$

$$= 8 \times 75 / \pi^2$$
(21)

Since the switching frequency is 50 KHz

$$\frac{1/2 \sqrt{L_s / C_s} = 50 \times 10^3}{\sqrt{L_s} = 60.8 \sqrt{C_s}}$$

$$\sqrt{C_s} = \sqrt{L_s} / 60.8$$
(22)
$$\frac{1/2 \sqrt{L_s} \times \sqrt{L_s} / 60.8 = 50 \times 10^3}{\sqrt{C_s}}$$

$$60.8/2\pi \times L_s = 50 \times 10^3$$

from this



$$L_s = 185 \mu H$$
$$C_s = 0.052 \mu F$$

From the availability of the capacitors, is in chosen as  $0.05\mu$ F.The inductance Ls is obtained as  $202\mu$ H. In the experimental setup, the actual inductance used is  $200\mu$ H, which is close to the designed value.

# 6. Simulation of LcLResonant Full Bridge Converter

The simulated circuit of LCL Resonant Full Bridge Converter is shown in Figure 4.

Power MOSFET, are used as switches M1, M2, M3 and M4 in the converters for an operating frequency of 50KHz. The anti parallel diodes, D1, D2, D3 and D4 connected across the switches are not need because they have inherent anti-parallel body diodes. The forward current and the reverse voltage ratings of the diode are the same as the current and voltage ratings of the MOS-FET. The internal diode is characterized by forward voltage drop and reverse recovery parameters like a discrete diode.

The resistor, inductor, capacitors, the power diodes and the power MOSFET'S are represented by their PSPICE Model. MOSFET IRF 330 is selected as the switching device which meets the peak current and voltage requirements.



Figure 4. LCL resonant converter circuit.

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#### Figure 5. Flow chart for embedded controller 89C51.

DIN 4001 is chosen as the power diode which meets the requirements. Using the datasheets for the POWER MOSFET IRF 330 and the power diode – DIN 4001, given in appendix (A), the various parameters of the model are calculated and used in the circuit file. The simulated waveforms of  $V_{Ls}$ ,  $V_{L_P}$ ,  $V_{Cs}$ ,  $I_{L_P}$ ,  $I_{Cs}$ ,  $V_{A_B}$ , and  $V_0$  found to agree with the analytical results to an appreciable degree.

### 7. About Keil

It is software, which is used to check the embedded C program and results that whether the program is correct or not, which is shown in Figure 6.

### 8. Conclusions

A modified SRC which employs a LCL-Resonant Full Bridge Converter circuit and operating above resonance (lagging power factor) mode has been presented. This converter with a voltage type load shows it provide load independent operation above the resonance frequency. So, the switching power losses are minimized. This new DC-DC converter has achieved improved power densities for air borne applications. This converter analyzed by using state space analysis is presented. The LCL resonant full bridge converter is potentially suited for applications such as space and radar high voltage power supplies with the appropriate turns ratio of high frequency transformer. Another good feature of this converter is that the converter operation is not affected by the non idealities of the output transformer (magnetizing inductance) because of the additional resonance inductor L<sub>P</sub>.

Table 2. Comparison of PSPICE simulation, theoretical & experimental results obtained from the model for a 133W, 50 KHZ DC-DC LCL resonant converter.

	(	(Volts)	(Volts)
1.5625	127.9	125	127
1.556	128.5	125	127.5
1.554	128.7	125	128.1
1.55	129	125	128.7
1.548	129.2	125	129
1.548	129.2	125	129
1.548	129.2	125	129
1.548	129.2	125	129
	1.5625 1.556 1.554 1.555 1.548 1.548 1.548 1.548	1.5625       127.9         1.556       128.5         1.554       128.7         1.55       129         1.548       129.2         1.548       129.2         1.548       129.2         1.548       129.2         1.548       129.2         1.548       129.2         1.548       129.2	1.5625127.91251.556128.51251.554128.71251.551291251.548129.21251.548129.21251.548129.21251.548129.21251.548129.21251.548129.2125

(Ls =	= 185 <b>uH.</b> Cs =	$= 0.052  \mu F. C =$	0.0087 uF. Lp =	200 uH. Co =	= 1000 uF. Load	L=10uH. E=10	V. Input Voltage = 10	0 V)
(~	,		···········	,			· , · · · · · · · · · · · · · · · ·	· · /

From Table 2, it is known that the hardware result for open loop LCL resonant converter varies from 127 V to 129V. But theoretical result should not go beyond 125V. So there is a scope for future extension.

The LCL-resonant full bridge converter is simulated by using PSPICE software. The simulation is carried out for  $120\mu$ S which is equivalent to six cycles, and simulation results are obtained. The triggering circuit of LCL-RFB converter is also simulated by using PSPICE software. The hardware implementation of triggering circuit and the power circuit are obtained and the results are compared to the simulation results.

### 9. Scope of Future Extension

Analysis, design, simulation and fabrication of closed loop LCL resonant converter.

Comparison result of open loop and closed loop LCL resonant converter.

🕵 µ¥ision/51 evaluation - PRO1.Pl	RJ
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{ int a,b,c,d,i;	
P0=a,b; P1=c_d	
P0=1;	
+or(1=1;1<=200;1++); P0=0;	Project Status (PR01.PRJ)
P1=1; for(i=1:i<=200:i++):	Source File: PRO1
}	Object File: PRO1.HEX
	Total Time: 00:00:01
	Status: Make Successful HEX File Created
	<u> </u>
4	

Figure 6. Program result for embedded controller output using Keil software.



Figure 7. Prototype model -embedded control of LCL resonant converter.



Figure 8. Experimental results of gate voltage (X axis represents time in micro seconds and Y axis represents Gate Voltage. The amplitude is 5V. If M1 & M4 conduct 0-20µs then M1 & M4 are in OFF State. If M2 & M3 conduct 20µs - 40µs then M2 & M3 are in OFF State).



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Figure 9. Experimental results obtained from the model for a 133W, 50 KHZ DC-DC LCL Resonant Converter output voltage = 127. 5 V (Ls =  $185\mu$ H, Cs =  $0.052 \mu$ F, C =  $0.0087 \mu$ F, Lp =  $200 \mu$ H, R=  $20\Omega$ , Co =  $1000 \mu$ F, Load L= $10\mu$ H, E=10V, Input Voltage = 100 V).

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